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Nicole M. Fernandez, Alida Perez-Fodich, Louis A. Derry, Jennifer L. Druhan. A first look at Ge/Si partitioning during amorphous silica precipitation: Implications for Ge/Si as a tracer of fluid-silicate interactions. Geochimica et Cosmochimica Acta, 2021, 297, pp.158-178. 10.1016/j.gca.2021.01.007 . insu-03590083

HAL Id: insu-03590083 https://insu.hal.science/insu-03590083

Submitted on 13 Feb 2023 $\,$

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A first look at Ge/Si partitioning during amorphous silica precipitation: Implications for Ge/Si as a tracer of fluid-silicate interactions

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11 ABSTRACT

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12 We measured germanium-silicon (Ge/Si) ratios in both fluid and solid phases using a series of highly constrained amorphous silica precipitation experiments at 20°C and neutral 13 pH for a wide range of seed crystal surface areas. Silicon isotope data ($\delta^{30/28}$ Si) on these 14 experiments were previously reported by Fernandez et al. (2019). A distinct lag in the onset of 15 16 Ge/Si partitioning relative to δ^{30} Si fractionation during active amorphous silica growth 17 indicated that Ge incorporation rates were orders of magnitude slower than silicon 18 precipitation rates. Slow Ge kinetics give the appearance of conservative behavior over short 19 experimental timescales (~30 days). A major outcome from these observations was the existence of distinct equilibration timescales between Ge/Si and δ^{30} Si. Further, these 20 21 experimental results provide the first documented evidence of rate dependent behavior in Ge 22 partition coefficients. Successful application of a modified solid solution model, initially 23 developed for characterizing stable isotope fractionation, indicates that a common fractionation model theory is able to describe both Ge/Si and δ^{30} Si partitioning. Numerical 24 25 simulations conducted at longer timescales (1 to 1000 years) predict eventual Ge incorporation into the mineral surface, but this occurs when the system is in close proximity 26 to equilibrium conditions. These long-term predictions underscore the potential of Ge as a 27

28 (near)equilibrium tracer in complement to the mixed kinetic and equilibrium signatures 29 recorded by δ^{30} Si. Our findings illustrate the viability of a combined Ge/Si– δ^{30} Si multi-tracer 30 approach for constraining silicate mineral formation across a variety of terrestrial and marine 31 systems.

32

33 1. INTRODUCTION

Shared characteristics between trace element Germanium (Ge) and major element Silicon 34 (Si) make germanium to silicon (Ge/Si) ratios valuable tracers of the global silicon cycle 35 (Mortlock and Froelich, 1987; Murnane and Stallard, 1990; Froelich et al., 1985, 1992; 36 37 Hammond et al., 2000; King et al., 2000; Kurtz et al., 2002; Derry et al., 2005; Baronas et al., 38 2018). Ge and Si are both group IV elements and have similar electronic configurations as 39 both reside within the "p-block' of the periodic table. They have similar oxygen bond lengths (Si–O and Ge–O are 1.75 and 1.64 Å, respectively) and are of similar sizes, where Ge is 40 slightly larger (atomic radius = 0.53 Å) compared to Si (atomic radius = 0.41 Å). These 41 42 common atomic properties facilitate the incorporation of Ge into secondary silicate phases as 43 a substitute for Si in the same manner commonly observed for other pseudo-isotope trace 44 replacements, such as Sr for Ca in carbonates, following Goldschmidt's principle 45 (Goldschmidt, 1926, 1958). In this respect Ge can be considered as a pseudo-isotope of 46 silicon, imitating Si behavior across the biogeochemical Si cycle from the chemical 47 weathering of rocks to the uptake of diatoms in the oceans and throughout long-term storage as deep marine sediments. Like the silicon stable isotope (δ^{30} Si) tracer, Ge/Si ratios are 48 49 partitioned due to a distinct subset of biogeochemical processes, notably secondary mineral 50 formation, biological uptake, and adsorption onto Fe-(hydr)oxides. These pathways cause Ge 51 to partition from Si based on compatibility and substitution mechanisms just as they invoke mass dependent fractionations between heavy ³⁰Si and light ²⁸Si isotopes (Opfergelt et al., 52

55 coefficient
$$\left(K_D = \frac{Ge_{Si\,product}}{Ge_{Si\,reactant}}\right)$$
. This is comparable to δ^{30} Si fractionation, described by a

56 fractionation factor
$$\left(\alpha = \frac{R_{product}}{R_{reactant}}\right)$$
 where $R = \frac{{}^{30}Si}{{}^{28}Si}$.

57 In natural environments, congruent mineral dissolution is not associated with any systematic δ^{30} Si or Ge/Si fractionation (Wada and Wada, 1982; Kurtz et al., 2002). Abiotic 58 silicate mineral precipitation is a major fractionating pathway for both δ^{30} Si (Ziegler et al., 59 2005a,b; Georg et al., 2006, 2007, 2009; Opfergelt et al., 2012; Pogge von Strandmann et al., 60 2012; Hughes et al., 2013; Riotte et al., 2018; and others) and Ge/Si (Kurtz et al., 2002; 61 Scribner et al., 2006; Lugolobi et al., 2010; Aguirre et al., 2017; Ameijeiras-Marino et al., 62 63 2018; Qi et al., 2019; Perez-Fodich and Derry, 2020). This process distinguishes the 64 compositions of the forming solid phase and surrounding fluid as a function of the rate and 65 extent of mineral growth.

Ge/Si and δ^{30} Si have been shown to co-evolve under terrestrial weathering conditions 66 67 (Lugolobi et al., 2010; Opfergelt et al., 2010; Delvigne et al., 2016; Baronas et al., 2018, 2020) and, for the most part, the manner in which they fractionate is thought to be 68 69 comparable. For secondary clays, δ^{30} Si and Ge/Si signatures are typically inversely correlated 70 in that the light ²⁸Si is preferentially incorporated into the newly-formed clay due to kinetic 71 isotope effects and Ge is similarly preferentially partitioned into the solid phase as a result of compatibility with secondary clays at equilibrium ($K_d \sim 10.7$ on average for secondary clays; 72 Kurtz et al., 2002). The result is a secondary clay low in δ^{30} Si, ranging from -2.95 to -0.16 %. 73 74 (Ziegler at al., 2005a,b; Georg et al., 2006; Cornelis et al., 2010; Opfergelt et al., 2012; Hughes et al., 2013. Frings et al., 2016; Riotte et al., 2018; and others) and elevated in Ge/Si, 75 reaching values greater than 5 µmol mol⁻¹ (Kurtz et al., 2002; Lugolobi et al., 2010; Opfergelt 76

et al., 2010; Aguirre et al., 2017; Ameijeiras-Marino et al., 2018; Qi et al., 2019). Thus, the fluid from which these mineral phases form must become isotopically heavier (i.e., higher δ^{30} Si values) and lower in Ge/Si with respect to the bedrock or minerals which were originally solubilized.

Some circumstances cause distinct δ^{30} Si and Ge/Si behavior. Notably, δ^{30} Si and Ge/Si are 81 decoupled from one another during uptake by vascular plants, where light ²⁸Si is 82 83 preferentially incorporated into the phytoliths while Ge is generally excluded. This results in high soil water Ge/Si and δ^{30} Si and correspondingly lower values in phytoliths (Blecker et al., 84 85 2007; Derry et al., 2005; Meek et al., 2016). Despite these noted exceptions, we generally anticipate that the underlying fractionation mechanisms for δ^{30} Si and Ge/Si are inherently 86 87 analogous during mineral neoformation (similar to that proposed for Ca stable isotopes and 88 Sr/Ca ratios; DePaolo, 2011). However, despite numerous examples of δ^{30} Si and Ge/Si co-89 evolution in the field, the behavior of these two tracers during secondary silicate precipitation 90 has yet to be directly demonstrated.

To explore the extent to which δ^{30} Si and Ge/Si fractionation are influenced by both 91 92 kinetic and equilibrium effects, including the potential for co-evolution of the mineral surface 93 and fluid in the transition from kinetically controlled to near-equilibrium conditions, we 94 analyzed samples from a series of highly constrained amorphous silica precipitation 95 experiments recently reported by Fernandez et al. (2019). This approach leveraged the 96 relatively rapid kinetics of amorphous silica formation (Geilert et al., 2014; Roerdink et al., 2015) to document δ^{30} Si fractionation behavior under variable or "free-drifting" conditions 97 98 (i.e., where saturation states and solute compositions are allowed to change with reaction 99 progress) across a range of seed crystal specific surface areas (e.g., a range of growth rates) 100 and solid to fluid ratios. The study showed clear evidence for kinetic isotope fractionation 101 followed by rapid isotopic re-equilibration as a function of the overall precipitation rate and,

4

102 thus, by extension the surface area of seeds used in the experiments. In this context, the 103 mechanisms of δ^{30} Si fractionation during amorphous silica precipitation were comparable to 104 that of δ^{44} Ca during carbonate formation (Tang et al., 2008; DePaolo 2011). But, due to the 105 free drift nature of the experiments, these data were shown to depend on both chemical 106 (saturation state, solute compositions) and physical (surface area, solid to fluid ratio) 107 characteristics of the system. Thus, the utility of the silicon isotopic tracer incorporates a 108 variety of physiochemical effects and parsing this signature in natural settings could pose a 109 poorly constrained problem if and when all factors are varying.

110 Viewed in this way, the analogous behavior of Ge/Si ratios offer a promising tool to 111 complement δ^{30} Si if the factors affecting this signature can be similarly constrained within a 112 unified model framework. To test whether δ^{30} Si and Ge/Si follow analogous fractionation 113 pathways for amorphous silica formation, we applied a numerical multi-component 114 geochemical model adapted from the principles of the SRKM (surface reaction kinetic model) 115 proposed by DePaolo (2011) to our "free-drift" experimental data. This model framework has 116 been successfully used in the past to describe δ^{44} Ca and Sr/Ca fractionation in calcite 117 precipitation experiments (Tang et al., 2008; AlKhatib and Eisenhauer, 2018) and has been recently applied to describe δ^{30} Si fractionation during amorphous silica formation (Roerdink 118 119 et al., 2015; Fernandez et al., 2019).

120 This study reports the first direct documentation of the extent of Ge incorporation and 121 Ge/Si fractionation during active amorphous silica precipitation under highly constrained 122 laboratory conditions. This experiment is the first, to our knowledge, to directly parse the 123 effects of kinetically limited mineral growth on Ge/Si relative to δ^{30} Si signatures. Our 124 findings have direct implications for interpretation of Ge/Si ratios observed in a variety of 125 field settings where amorphous silica precipitation exerts a large control on silicon 126 (bio)geochemical cycling. Examples include silicate weathering in the critical zone,
127 hydro(geo)thermal activity, and marine diagenesis and recrystallization.

128 **2. METHODS**

129 **2.1 Batch experiments**

130 The samples analyzed in this study were generated from amorphous silica precipitation 131 batch experiments reported in Fernandez et al. (2019). We refer the reader to this prior 132 publication for complete descriptions of the experimental design and initial conditions. To 133 summarize, amorphous silica precipitation experiments were conducted in three closed batch 134 reactors each with a different set of SiO_{2(s)} seed crystal surface areas and solid to fluid silicon mass ratios (50 to 31 SiO_{2(s)} [g]:SiO_{2(aq)}[g]) at an ambient temperature of 20°C. All 135 136 experiments started at a comparable dissolved $SiO_{2(aq)}$ concentration (5.3 mM) and pH (7.3) 137 and were run for approximately 30 days, resulting in an initial oversaturation of 0.48 ± 0.06 138 $(\log Q/K)$ with respect to SiO_{2(s)}. Each batch reactor contained one of three seed crystal grain sizes, with specific surface areas that will from now on be referred to as high (SSA = $50 \text{ m}^2 \text{ g}^-$ 139 ¹), medium (SSA = $0.127 \text{ m}^2 \text{ g}^{-1}$), and low (SSA = $0.072 \text{ m}^2 \text{ g}^{-1}$) experiments. Initial seed 140 141 Ge/Si ratios for the high, medium, and low surface area grains were $0.28 \pm 0.01 \,\mu\text{mol mol}^{-1}$, $0.56 \pm 0.02 \ \mu mol \ mol^{-1}$, and $0.64 \pm 0.02 \ \mu mol \ mol^{-1}$, respectively. Starting oversaturated 142 143 solutions were prepared by dissolving 10 g of high surface area fumed silica grains in 1L of 144 MQ-e water at 90°C for ~1 week until starting SiO_{2(aq)} concentration were reached. Ge was 145 introduced through leaching via the dissolution of these high surface area seeds (Ge/Si = 0.28146 $\pm 0.01 \,\mu$ mol mol⁻¹) at 90°C, resulting in a starting Ge:Si content in the fluid of 0.044 ± 0.002 147 μ M : 0.00530 ± 0.00003 M (initial fluid Ge/Si ratio = ~8.45 ± 0.3 μ mol mol⁻¹). The difference in seed crystal and starting solution Ge/Si ratios is discussed further in section 4.1. 148

149 The next steps in the preparation of the starting solution followed different protocols 150 depending on the type of surface area seeds used in each batch. For the batch involving high 151 surface area seeds, the starting solution after the pre-dissolution step at 90°C was cooled 152 directly to 20°C. In the medium and low surface area batches, the starting solutions were 153 subjected to vacuum filtration to remove the undissolved high surface area grains and 154 subsequently cooled to 20°C. In all batches, initially acidic solutions (pH \sim 4.5) were then 155 titrated with 10 mM NaOH to the target starting pH (7.3). This increase in pH to near-neutral 156 values was sufficient to initiate precipitation in the high surface area case. For the low and 157 medium surface area cases, amorphous silica seed crystals of appropriate size were also added 158 in order to start the reaction. In all batches, precipitation occurred onto pre-existing grains 159 homogeneously distributed in solution with starting masses of approximately 4 g for the 160 medium and low surface area batches and 0.5 g for the high surface area batch. Experiments 161 were run for a duration of ~ 30 days while being continuously agitated on a shaker plate. 162 Samples were withdrawn at regular time intervals in aliquots of 2.5mL using a disposable 163 syringe and 0.22µm nylon filter. A fraction of the sample (2 mL) was subsequently diluted to 164 10 mL with ultrapure water in preparation for silicon stable isotope and Ge concentration 165 analyses. Experiments were terminated after the last sample was taken and amorphous silica 166 grains were separated out of the remaining solution via vacuum filtration. Initial experimental 167 conditions across all seed crystal surface areas are reported in Table 1.

168 **2.2 Germanium analyses**

Germanium concentrations were analyzed using hydride-generation ICP massspectrometry (HG-ICP-MS) (Mortlock & Froelich, 1996; Aguirre et al. 2017) at Cornell University with a custom HG sample introduction system and a Thermo-Finnigan Element 2 ICP-MS. Aqueous samples were prepared by adding an enriched ⁷⁰Ge spike solution and allowed to equilibrate for at least 48 hours at room temperature. The spike solution was added to target a 70 Ge/⁷⁴Ge ratio of 10, estimated from the Si concentrations. To measure Ge concentrations, the prepared samples were introduced into the hydride generation system with 176 a 4% NaBH₄ solution to reduce aqueous Ge(OH)₄ to volatile GeH₄, passing through an gasliquid-separation filter along with Ar as carrier gas into the ICP-MS. Germanium was 177 quantified by isotope dilution using the ⁷⁰Ge/⁷⁴Ge ratio. Mass bias and signal drift were 178 179 corrected using standard sample bracketing. We measured Ge standards at 5, 20, 50, 100 and 180 200 ng L⁻¹. To cross-check the isotope dilution calculations, standard response curves were generated at m/z =74 for each Ge concentration. The 70 Ge/ 74 Ge in the spike is equal to 162, 181 thus the contribution from the spike at m/z = 74 is insignificant. Analytical uncertainty for 182 183 these measurements is approximately 3% RSD (Kurtz et al., 2002; Derry et al., 2005; 184 Lugolobi et al., 2010; Kurtz et al., 2011). The contribution of the spike addition to the 185 uncertainty of Ge measurements is negligible (Heumann, 1988).

186 **2.3 Model design and assumptions**

187 Ge partitioning during amorphous silica precipitation was simulated using the multi-188 component reactive transport software, CrunchTope (Steefel et al., 2015). The fractionation 189 model framework within CrunchTope uses a two-endmember solid solution (Druhan et al., 190 2013) to create a simple, binary mechanical mixture between two substituting elements in a 191 solid phase such as rare and major isotopes of a major element (ex. ${}^{28}Si_{1-x}{}^{30}Si_{x}O_{2(am)}$) or trace 192 and major elements (ex. $Si_{1-x}Ge_xO_{2(am)}$), where x represents the mole fraction of either the rare 193 isotope or trace element. For the purposes of the current study, an ideal solid solution 194 between amorphous GeO_2 and SiO_2 takes the following form (Eq. 1):

195
$$(1-x)Si(OH)_{4(aq)} + xGe(OH)_{4(aq)} \rightleftharpoons (Si_{(1-x)}Ge_x)O_{2(am)} + 2H_2O$$
 (1)

where Ge in the form of $Ge(OH)_{4(aq)}$ species in solution is shown substituting for Si in amorphous silica, $SiO_{2(am)}$, in this solid solution stoichiometry and *x* represents the mole fraction of $GeO_{2(am)}$. In an ideal solid solution each element (in the case of isotopes, each individual isotope), can substitute for one another in the same site within the crystal structure with negligible changes to the thermodynamic (i.e., entropy of mixing) or physical (i.e., molar 201 volume) aspects of a growing mineral phase (Gresens, 1981; Anderson and Crerar, 1993). 202 Thus, for an ideal solid solution the sum of the activity coefficients must equal 1. Under this 203 ideal solid solution assumption, the mole fraction, x, can then be treated as a variable, which 204 allows for the traditional net TST (transition state theory) rate laws to be recast such that each 205 endmember component can be treated individually as shown below (Eq. 2):

206
$${}^{Ge}R_{p} = {}^{Ge}X^{Ge}k_{f}A\left(\frac{Ge(OH)_{4(aq)}}{{}^{Ge}X^{Ge}K_{eq}} - 1\right)^{m}$$
(2a)

207
$${}^{Si}R_{p} = {}^{Si}X^{Si}k_{f}A\left(\frac{Si(OH)_{4(aq)}}{{}^{Si}X^{Si}K_{eq}} - 1\right)^{m}$$
(2b)

$$^{i}X = \frac{n_{Si,Ge}}{n_{Si} + n_{Ge}}$$
(2c)

where the individual TST rate laws (in units of mol s^{-1}) displayed for Ge (^{Ge}**R**_p, Eq. 2a) and Si 209 (^{Si}**R**_p, Eq. 2b) are coupled by the mole fractions for $GeO_{2(am)}$ and $SiO_{2(am)}$, ⁱX (i = Si, Ge), 210 211 defined by the number of moles of either Ge or Si (n_{Ge,Si}) over the total moles of amorphous 212 silica present (Eq. 2c). These rate equations are dependent on the total surface area of the amorphous silica grains (A, [m²]), the rate constants (ⁱk_f, [moles m⁻² s⁻¹]), the relative 213 activities of the major $(Si(OH)_{4(aq)})$ and trace element $(Ge(OH)_{4(aq)})$ in solution and their 214 215 respective equilibrium constants (${}^{i}K_{eq}$). The affinity dependence, *m*, is set to 3.5 in this model, 216 based on a sensitivity analysis of the reaction order term (which can range from 1 to > 5 for 217 amorphous silica precipitation, Iler, 1979; Rimstidt & Barnes, 1980; Fleming, 1986; Tobler et 218 al., 2009) performed in Fernandez et al. (2019) for the same experiments. To our knowledge, there is no direct constraint for the value of m across a solid solution between Si and Ge or 219 220 any other comparable system. Thus, the same reaction order term is imposed for both Si and 221 Ge rate equations to respect the formalism of the ideal solid solution condition and to 222 maintain consistency with the Fernandez et al. (2019) model. Kinetic and equilibrium

223 partition coefficients for Ge, D_{kin} and D_{EQ}, are defined in this model formulation by the ratio

of the precipitation rate constants $\left(\frac{Ge_{k_f}}{Si_{k_f}}\right)$ and equilibrium constants $\left(\frac{Ge_{K_{eq}}}{Si_{K_{eq}}}\right)$, respectively, and are distinct from the overall or 'effective' partition coefficient K_D $\left(\frac{Ge/Si_{solid}}{Ge/Si_{fluid}}\right)$ defined in section 1.

227 This model follows the same fractionation framework initially developed for stable 228 isotopes (Druhan et al., 2013) and successfully applied to Si stable isotope fractionation for 229 the same amorphous silica growth experiments (Fernandez et al., 2019). Importantly, the 230 application of this model to Ge/Si during amorphous silica growth assumes that the behavior 231 of Ge trace element partitioning is analogous to silicon stable isotopes, as has been indicated previously for other systems such as δ^{44} Ca and Sr/Ca during calcite growth. Here, for the first 232 time, we directly test such commonality for the δ^{30} Si and Ge/Si system. This numerical 233 234 modeling approach notably allows both fluid and solid phase trace element ratio (Ge/Si) 235 compositions to evolve through time via coupled net precipitation rates and mole fractions 236 (Eq. 2) within an ideal solid solution framework. For stable isotopes, the underlying 237 assumptions for the mole fraction are valid because isotopic substitution into the crystal 238 structure of a growing solid phase is one of the closest approximations to a true ideality 239 (Anderson and Crerar, 1993). However, application of the same model to Ge requires 240 consideration of the appropriateness of this ideal solid solution assumption.

241

2.3.1 The ideal Ge – Si solid solution

The validity of an ideal Ge–Si solid solution for amorphous silica is essentially unknown due to the lack of available thermodynamic information. Shared chemical properties (valence state and inorganic aqueous speciation) between Ge and Si implies that Ge substitution for Si could be reasonably approximated as ideal during secondary silicate formation (Capobianco and Watson, 1981; Capiobianco and Navrotsky, 1982; Martin et al., 1996; Pokrovski and Schott, 1998). This recently led Perez-Fodich and Derry (2020) to assume ideality for Ge–Si mixing behavior during kaolinite formation. For the current study (amorphous SiO₂–GeO₂ solid solution) two observations are particularly relevant in our justification of ideality. First, calorimetric data from the Capobianco and Watson (1981) experimental study of Ge partitioning in sodium feldspars indicate that amorphous glasses tend to conform better to an ideal solid solution than their crystalline counterparts. Second, Evans and Derry (2002) found that an ideal solid solution model adequately described the behavior of Ge and Si during hydrothermal quartz precipitation.

Furthermore, Ge/Si in most natural systems is near 10^{-6} whereas 30 Si/ 28 Si is near 0.031, so while Ge is likely to substitute less readily for 28 Si than 30 Si, its relative abundance is 4 orders of magnitude lower. With a molar ratio of 10^{-5} to 10^{-6} between Ge and Si in silicates, such a system approaches the Henry's Law limit of ideal behavior, even when higher concentrations would lead to non-ideality. Thus, an ideal solid solution is a reasonable assumption for Ge–Si binary mixing during amorphous silica growth.

261

2.3.2 Trace element model parameterization

262 In this model approach, Ge is treated in the same manner as a rare isotopologue in a 263 stable isotope system, albeit with some important distinctions. For instance, in the treatment of stable isotopes in this framework, the activities of the individual isotopes (²⁸Si and ³⁰Si) 264 265 must sum up to overall activity of Si in solution. But for trace elements, the activities of Ge 266 and Si are considered independent. Consequently, the kinetic and thermodynamic parameters 267 of both amorphous SiO₂ and GeO₂ must be acquired individually. Amorphous silica is 268 fortunately well-studied, and an abundance of kinetic and thermodynamic data are available 269 from a multitude of carefully conducted laboratory studies (Rimstidt & Barnes, 1980; 270 Fleming, 1986; Gurnarsson and Arnórsson, 2000, Tobler et al., 2009; Geilert et al., 2014; 271 Roerdink et al.2015; Oelze et al.2015; Stamm et al., 2019; Fernandez et al., 2019). Thus, for SiO₂, the precipitation rate and equilibrium constants at 20°C are well constrained with values 272

of 10^{-9.67} moles m⁻² s⁻¹ (Rimstdt and Barnes, 1980) and 10^{-2.7135} (Gunnarsson and Arnórsson, 273 2000), respectively. This makes parameterization of Eq. 2a straightforward, as was done in 274 275 Fernandez et al. (2019) for the silicon isotope model. Parameterizing Eq. 2b, however, is 276 more complicated. Experimentally determined thermodynamic data for germanates are scarce 277 and only exist for a few minerals including argutite (GeO_{2(hex)}) (Arnórsson 1984; Pokrovski 278 and Schott, 1998) and some chain and phyllo-silicates (Pokrovski and Schott, 1998 and 279 Shtenberg et al., 2017 respectively). We are not currently aware of any kinetic data that exists 280 for the formation of $GeO_{2(am)}$. Lacking this necessary data, we rely on estimates for both 281 kinetic and thermodynamic parameters based on our experimental results and the known K_D 282 value of crystalline SiO₂ and GeO₂ phases, respectively.

For the amorphous germanium oxide (GeO_2) solubility constant, any equilibrium partitioning between Ge/Si across equilibrated fluid and solid phases implies that this value is not precisely equal to its SiO₂ counterpart. Assuming applicability to an amorphous solid, we apply the equilibrium model for an ideal binary mixture between crystalline quartz (SiO₂) and arguite GeO₂, Ge_xSi_{1-x}O₂ given by Evans and Derry (2002), which states that:

288
$$\operatorname{GeO}_{2(\operatorname{am})} + 2\operatorname{H}_20 \rightleftharpoons \operatorname{GeOH}_{4(\operatorname{aq})}$$
 (3a)

289
$$\operatorname{SiO}_{2(am)} + 2H_20 \rightleftharpoons \operatorname{SiOH}_{4(aq)}$$
 (3b)

290
$${}^{\text{Ge}}\text{K}_{\text{eq}(am)} = \frac{a_{\text{Ge}(OH)_{4}(aq)}}{a_{\text{Si}(OH)_{4}(aq)}} \times \frac{s_{iX}}{s_{eX}} \times {}^{\text{Si}}\text{K}_{\text{eq}(am)} = \frac{(\text{Ge}/\text{Si})_{\text{fluid}}}{(\text{Ge}/\text{Si})_{\text{solid}}} \times {}^{\text{Si}}\text{K}_{\text{eq}(am)}$$
(3c)

291
$${}^{Ge}K_{eq(am)} \approx \frac{{}^{Ge}K_{sp, argutite}}{{}^{Si}K_{sp, quartz}} \times {}^{Si}K_{eq(am)} = D_{EQ(qtz-argutite)} \times {}^{Si}K_{eq(am)}$$
(3d)

where for Eq. 3a to Eq. 3c, $a_{Ge(OH)4}$ and $a_{Si(OH)4}$ are the activities of germanic and silicic acid at equilibrium, ^{Si}X and ^{Ge}X are the mole fractions of the SiO₂ and GeO₂ solid phases, and ^{Si}K_{eq(am)} is the solubility constant for amorphous silica (10^{-2.7135} M; Gunnarsson and Anórsson, 2000). Through the combination of Eq. 3a and Eq. 3b we can estimate the equilibrium constant for amorphous GeO₂ (Eq. 3c). The known equilibrium partition coefficient between

quartz and argutite ($D_{EQ} = {}^{Ge}K_{eq(argutite)} / {}^{Si}K_{eq(quartz)}$) is defined by their relative equilibrium 297 constants of 10^{-3.9582} M (Rimstidt and Barnes, 1980) and 10^{-5.0645} M (Pokrovski et al., 2005) 298 respectively at 25°C. Assuming a comparable partitioning for the amorphous phases and the 299 known solubility constant for amorphous silica, ^{Si}K_{eq(am)}, the equilibrium constant for 300 amorphous GeO₂ ($^{Ge}K_{eq(am)}$) is estimated to be 10^{-3.8198} M (Eq. 3d). Thus, D_{EQ} for amorphous 301 302 silica using the equilibrium model is 0.08, which corresponds to an "effective" partition coefficient $\left(K_D = \frac{(Ge/Si)_{solid}}{(Ge/Si)_{fluid}}\right)$ of 12.8 through the expression $K_D \approx \frac{1}{D_{EQ}}$ (Eq. 3c,d). A K_D of 303 12.8 indicates that amorphous silica at equilibrium should have a final Ge/Si ratio 12.8× 304 305 higher than the fluid.

306 Ge kinetics during amorphous silica formation are estimated via a best-fit 307 approximation and sensitivity test using the experimental data reported in this study (**section** 308 **4.2**). Ge batch model simulations for amorphous silica precipitation were performed for a 309 range of timescales (35 to 1000 years), surface areas (0.072 to 50 m² g⁻¹), and Ge precipitation 310 scenarios using identical starting fluid and solid phase Ge/Si ratios, temperature, and pH.

311 **3. RESULTS**

312 **3.1 Time evolution of Ge/Si**

313 Measured fluid and solid phase Ge/Si ratios (denoted as (Ge/Si)fluid and (Ge/Si)am.silica, 314 respectively; Table 2), monitored over the experimental duration from 0 to 30 days (Fig. 1), are presented alongside measured dissolved Si concentrations and their corresponding δ^{30} Si 315 316 values for the high, medium, and low surface area experiments reported by Fernandez et al. 317 (2019). Dissolved silica concentrations (Fig. 1A) decrease with time for all experiments until 318 a metastable equilibrium is attained with respect to the amorphous silica solubility 319 concentration at 20°C (Gunnarsson and Anórsson, 2000; Fernandez et al., 2019). 320 Correspondingly, fluid Ge concentrations (Ge(OH)₄, Table 2) remained relatively constant 321 with time from a starting concentration of 44788 ± 1750 pM (1SD, n = 3) to a final 322 concentration of 41129 ± 1989 pM (1SD, n = 3). Of the three batches, the high surface area showed the largest variability (Ge(OH)_{4,start} – Ge(OH)_{4,end} = 3921 ± 1156 pM). Time averaged 323 324 rates for Ge calculated based on the difference in concentrations over a given time interval (Eq. 5 in Fernandez et al. 2019) are ~5 orders of magnitude slower ($R_p^{Ge} = 10^{-14.3\pm0.6}$ mol m⁻² 325 s^{-1} , n = 3; Table 2) than Si precipitation rates ($R_p^{Si} = 10^{-8.9\pm0.5}$ mol m⁻² s⁻¹, n = 3; Table 2). For 326 327 all experiments (Ge/Si)_{fluid} ratios increase with time and subsequently stabilize at elevated 328 values after approximately 10 days (Fig. 1B). Low and medium surface area (Ge/Si)fluid values correlate strongly with the corresponding δ^{30} Si_{fluid}, effectively displaying the same 329 evolving behavior with time. In contrast, high surface area $(Ge/Si)_{\text{fluid}}$ and $\delta^{30}Si_{\text{fluid}}$ quickly 330 diverge as δ^{30} Si_{fluid} begins to isotopically re-equilibrate towards lower δ^{30} Si_{fluid} after roughly 1 331 day (Fernandez et al. 2019). Over the same period of time (Ge/Si)fluid ratios continue to 332 increase and ultimately stabilize to a final (Ge/Si)_{fluid} of ~18.95 µmol mol⁻¹, which is higher 333 than the medium (max (Ge/Si)_{fluid} = 14.40 μ mol mol⁻¹) and low (max (Ge/Si)_{fluid} = 12.04 μ mol 334 335 mol⁻¹) surface area batches, respectively.

336 Evolution of the bulk amorphous silica Ge/Si ratios ((Ge/Si)_{am.silica}, Fig. 1B) were calculated based on the cumulative mass of $SiO_2(N_{SiO_{2(ppt)}})$ where ppt = precipitate; Fernandez 337 et al., 2019) and GeO₂ ($N_{GeO_{2(ppt)}}$, Table 2) precipitated out of solution onto the pre-existing 338 339 seeds in the batch reactor. Mass balance calculations show (Ge/Si)_{am.silica} to slightly increase 340 throughout the extent of the reaction compared to the measured initial seed Ge/Si ratios 341 (Table 2). The high surface area batch shows the largest shifts in the growing amorphous silica Ge/Si, from initial value of $0.28 \pm 0.01 \ \mu mol mol^{-1}$ to a measured final value of 0.33 342 343 $\pm 0.02 \,\mu$ mol mol⁻¹, which is slightly greater than the analytical uncertainty. This shift to higher 344 (Ge/Si)_{am.silica} values was found to occur after ~1 day, by which time a majority of silica has 345 been precipitated out of solution (~45%). In comparison, the evolution of (Ge/Si)_{am.silica} for 346 the lower surface area batches falls within the uncertainty of the measurements ($\pm 0.02 \mu$ mol 347 mol⁻¹). The overall increase in the bulk composition observed in the high surface area
348 experiment, while statistically significant, is small compared with the measured changes in
349 (Ge/Si)_{fluid} as a function of time (Fig. 1B).

350 **3.2** δ³⁰Si vs. Ge/Si

The co-evolution of fluid δ^{30} Si and Ge/Si for all amorphous silica precipitation 351 experiments are plotted in Fig. 2. Starting at initial δ^{30} Si and Ge/Si values of approximately – 352 2% and 8.45 μ mol mol⁻¹ respectively, δ^{30} Si_{fluid} and (Ge/Si)_{fluid} both increase as a function of 353 354 reaction progress through the early stages of the experiments. For the medium and low surface area batches, δ^{30} Si_{fluid} and (Ge/Si)_{fluid} are linearly correlated ($\mathbf{R}^2 = 0.86$ and $\mathbf{R}^2 = 0.84$, 355 respectively). However, as observed in the timeseries plot (Fig. 1B), a reversal is noted in the 356 high surface area batch after ~1 day where fluid δ^{30} Si starts to decrease with time while 357 358 (Ge/Si)_{fluid} ratios continue to increase. This results in a substantial de-correlation between the high surface area δ^{30} Si_{fluid} and (Ge/Si)_{fluid} at later stages of the reaction. 359

360 **4. DISCUSSION**

361 **4.1** Origin of high starting (Ge/Si)_{fluid} and potential implications of an evolving reactive

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surface area during dissolution

363 Relatively constant Ge(OH)₄ concentrations throughout the experimental duration 364 coupled with rapid Si precipitation and elevated (Ge/Si)fluid values suggest that Ge exhibits 365 slow kinetics during amorphous silica precipitation. However, before proceeding further in 366 this interpretation, there are two alternative options that could explain the observed data. First, 367 we consider whether changes in the seed crystal surface area during the partial dissolution of 368 high surface area seeds at 90°C to prepare our starting solutions could have impacted the rate 369 of precipitation. In prior amorphous silica studies that served as the basis for our experimental 370 design (Geilert et al., 2014; Roerdink et al., 2015), this effect is minimized by using a large quantity of amorphous silica seeds for dissolution at 90°C (10 g L⁻¹). Results from mass 371

balance calculations indicate that only 1.65% of the total amount of amorphous silica seed
initially present was dissolved in order to reach Si solubility concentrations at 90°C (5.48
mM; Gunnarsson and Anórsson, 2000). A simplified geometric model relating mineral
concentration to changes in the reactive surface area (Lichtner, 1988; Noiriel et al. 2009)
suggests that this minor reduction in the solid phase should not impact the corresponding
surface areas of the seeds:

378
$$S = S_0 \left(\frac{C}{C_0}\right)^{-2/3}$$
 (4)

379 This formulation is based on a shrinking sphere model where S is the final surface area after dissolution (m² g⁻¹), S₀ is the starting surface area (50 m² g⁻¹), and C₀ and C corresponds to the 380 381 amount of silica in the amorphous phase present prior to and after dissolution (µmoles). The 382 calculation indicates an insignificant change in surface area ($\approx 0.002\%$). Furthermore, this 383 calculation reminds us that dissolution would increase the specific surface area of the 384 remaining seeds, thus speeding up the reaction and presumably allowing more Ge 385 incorporation into the growing solid. Although a simplified approach, Eq. 4 supports the 386 assumptions of Roerdink et al. (2015) and Fernandez et al. (2019) and we proceed with the 387 understanding that that changes to the surface area are not sufficient to affect our precipitation rates or the estimation of ${}^{\text{Ge}}k_{f}$ (eq. 2, section 2.3). 388

389 Second, we consider the potential for heterogeneity in the Ge content of the initial 390 amorphous silica seeds. If the initially elevated (Ge/Si)_{fluid} values were caused by dissolution 391 of a Ge-enriched rim coating our seed crystals, then rapid re-equilibration with this Ge-392 enriched surface layer could sustain high (Ge/Si)fluid values throughout the duration of the 393 experiment. However, several lines of evidence rebut this option as a likely explanation. To 394 start, the likelihood of amorphous silica seeds becoming strongly zoned during the fabrication 395 process is quite low. Assuming a zoned version of our high surface area seeds where the outermost surface has a Ge/Si ratio of ~ 8.45μ mol mol⁻¹, mass balance calculations suggest 396

397 that approximately 50% of the total Ge present in the solid would need to be concentrated in 398 the upper 0.32 nm of an individual grain perpendicular to its surface. This is smaller than the 399 size of a unit cell in an SiO₂ crystal structure (0.5405nm for α -quartz; Ackermann and Sorrel, 400 1974; Wright and Lehmann, 1981). Finally, high (Ge/Si)_{fluid} values with respect to the 401 dissolving mineral assemblage $(0.2 - 2.5 \mu mol mol^{-1})$ are systematically observed at elevated temperatures with values ranging from 2 to 1000 µmol mol⁻¹ (Arnórsson, 1984; Pokrovski and 402 403 Schott, 1998; Evans and Derry, 2002; Pokrovski et al., 2005; Escoube et al., 2015). Increasing 404 (Ge/Si)_{fluid} with increasing temperature can be attributed to preferential partitioning of Ge 405 with respect to Si arising from differences in the thermodynamic properties of $Ge(OH)_{4(aq)}$ 406 and Si(OH)_{4(aq)} (Pokrovski and Schott, 1998; Pokrovski et al., 2005). This high temperature 407 effect is not observed at ambient conditions characteristic of natural terrestrial weathering and 408 marine environments where (Ge/Si)_{fluid} reflects the composition of the dissolving silicate 409 rocks (Kurtz et al., 2002) and diatoms (Froelich et al., 1984, 1992; Mortlock et al., 1991), 410 respectively. However, our starting (Ge/Si)_{fluid} are consistent with a preferential Ge 411 partitioning during the pre-dissolution step at 90°C.

Regardless, even if the seeds were initially zoned, subsequent rapid re-equilibration with a Ge-enriched outer surface throughout the extent of the reaction is not possible. Mass balance calculations show that ~70% of the total Si lost from solution takes place over the first day, resulting in the formation of a strongly depleted Ge mineral surface that would effectively isolate the zoned interior from the fluid. Thus, the fluid would only be interacting and re-equilibrating with the recently-formed mineral surface and a strongly heterogeneous solid interior would have no effect on the overall (Ge/Si)_{fluid}.

Having ruled out these complicating effects, we conclude that Ge precipitation kinetics are slow relative to Si. This offers the simplest and most plausible explanation for our experimental results. However, in natural settings, it is observed that Ge is (eventually)

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422 incorporated into secondary silicates. To determine how slow Ge incorporation is during 423 amorphous silica formation, we now turn to the application of our trace model under the 424 assumption that our previous stable isotope fractionation framework (Fernandez et al. 2019) 425 also describes the partitioning of this trace element.

426 **4.2** Trace model: Ge exchange under a stable isotope fractionation framework

427 Observed fluid Ge/Si behavior during the amorphous silica growth experiments is 428 interpreted through a series of numerical simulations adapting the CrunchTope silicon isotope 429 fractionation model reported in our prior study (Fernandez et al. 2019) to a trace element. 430 Initial conditions for these numerical experiments are summarized in Table 3. Silica kinetic 431 and thermodynamic parameters for all simulations were kept constant with a log kinetic rate 432 and equilibrium constant of -9.67 (Rimstidt & Barnes, 1980) and -2.7135 (Gunnarsson and 433 Anórsson, 2000), respectively (Table 3). Potential factors that could influence amorphous 434 silica solubility concentrations and kinetic rates such as temperature and pH were minimized 435 via the experimental design. Further, the impact of the surface area and its evolution during 436 mineral growth on amorphous silica solubility was rigorously examined by Fernandez et al. 437 (2019) using the Freundlich-Ostwald equation (Enüston and Turkevich, 1960), finding no 438 significant changes in the solubility across the three surface area conditions.

439 The equilibrium K_D imposed ($D_{eq} = 0.08$, **Table 3**) derives from our estimated value 440 based on a quartz-argutite ideal solid solution (further details provided in section 2.3). The 441 kinetic rate constant for the incorporation of dissolved Ge in the solid as GeO_{2(am)} was 442 estimated by an optimization approach where the Ge kinetic rate parameter (log $k_{f(GeO2)}$; **Table 3**) was altered across a suite of numerical simulations (while keeping $K_{eq(GeO2)}$ and all 443 444 other parameters fixed) until an optimal value was found which provided the "best fit" to our 445 fluid Ge concentration data (Fig. 3). The range of kinetic Ge rate constants tested spanned roughly 6 orders of magnitude from a maximum rate of 10^{-12.6} mol m⁻² s⁻¹ (~3 orders of 446

447 magnitude slower than Si) to a minimum rate of $10^{-26.7}$ mol m⁻² s⁻¹ (~17 orders of magnitude 448 slower than Si). Our optimized Ge rate constant value was determined to be $10^{-19.7 \pm 1.1}$ mol m⁻² 449 s⁻¹, approximately 10 orders of magnitude slower than the Si kinetic rate constant ($10^{-9.67}$ mol 450 m⁻² s⁻¹; Rimstidt and Barnes, 1980). This yields a kinetic fractionation factor, **D**_{kin} (${}^{\text{Ge}}\mathbf{k}_{\text{f}}/{}^{\text{Si}}\mathbf{k}_{\text{f}}$), 451 of 9.33 × 10^{-11} . A Monte-Carlo sensitivity analysis performed over a broad kinetic and 452 equilibrium K_D parameter space further supports our combined estimates for K_{eq(GeO2)} and 453 k_{f(GeO2)} (**Appendix A**).

454 Flexibility in defining the component of the mineral that contributes to the mole 455 fraction (X) within the Ge trace model (section 2.3, Eq. 2) allows us to test several possible 456 Ge fluid-mineral mass exchange processes that could describe our observed Ge/Si 457 partitioning. Three Ge fluid-mineral exchange approaches (Druhan et al., 2013) were 458 explored in the model, designated respectively as (1) "no-back reaction", (2) "bulk", and (3) 459 "surface". In the "no back reaction" scenario, X is set to the aqueous mole fraction, which 460 decouples Ge and Si from each other (i.e. the precipitation rate is decoupled from the molar 461 fraction in the solid) and, thus, only a kinetic fractionation is imposed in the model (D_{kin}). In 462 this context, Ge and Si evolve irreversibly and the observed K_D reflects their individual 463 evolutions along their respective, unidirectional reaction pathways. In the "bulk" and 464 "surface" exchange scenarios the fluid and solid phases are allowed to equilibrate with one 465 another by defining X in terms of the solid mole fraction. Thus, D_{EO} is imposed in these 466 scenarios as opposed to the "no back reaction" case. The most straightforward approach is to 467 allow the fluid to interact with the total solid or "bulk" composition through time. However, 468 this "bulk" approach ignores the potentially significant impact of an evolving or zoning 469 mineral surface on observed fluid variability during "free-drift" mineral growth. Thus, a 470 "surface" approach was developed in an attempt to address this effect by allowing the fluid 471 to interact with only the portion of the mineral that has been most recently formed (Druhan et

al., 2013; Steefel et al., 2014; Fernandez et al., 2019). In this scenario, the depth into the 472 473 mineral surface in contact with the fluid (i.e., the fluid-mineral interaction depth) is 474 approximated through a running average of the composition of the mass recently precipitated 475 out of the fluid over a user-defined number of timesteps (details regarding this numerical 476 implementation can be found in Druhan et al., 2013 and Fernandez et al., 2019). This scenario 477 implies that the fluid-solid interaction depth varies as a function of reaction progress. This 478 varying fluid-solid interaction depth is an assumed underlying process which Fernandez et al. 479 (2019) successfully used to create a forward model of contemporaneous mineral surface and fluid δ^{30} Si evolution through time. Thus, we now extend this approach to the complementary 480 481 Ge/Si system.

482 **4.3** Ge partitioning over experimental timescales

483 The Ge trace model (Eq. 2) generally reproduces our measured fluid Ge/Si evolution 484 through time across the various surface area conditions (Fig. 4A). However, (Ge/Si)fluid 485 appears to be less sensitive to the different mass exchange scenarios ("no back reaction", 486 "bulk", and "surface") over the experimental duration compared to the contemporaneous Si 487 stable isotope ratios (Fig. 4B). This is particularly apparent in the low and medium surface 488 area cases in which net reaction rates are too slow to distinguish between these three Ge mass 489 exchange scenarios. The faster kinetics and subsequent re-equilibration of the high surface 490 area case create a greater response in the (Ge/Si)_{fluid} over the 1-month experimental timescale. 491 Thus, Ge is shown to exhibit quasi-conservative behavior during early (kinetically dominated) 492 stages of amorphous silica growth.

The most promising case for extracting information relevant to Ge incorporation and the fluid–mineral exchange mechanism underlying observed Ge partitioning lies in the high surface area experiment. In this case, the system evolved at fast enough rates to capture the beginning of non-conservative behavior as evidenced by overall greater sensitivity to the

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497 different fluid–mineral mass exchange scenarios (**Fig. 4A**). Application of a "**no-back** 498 **reaction**" model to the measured high surface area (Ge/Si)_{fluid} over-predicts the extent of 499 kinetic partitioning (in a manner comparable to that observed for δ^{30} Si, **Fig. 4B**). The 500 numerical simulation involving fluid equilibration with the "**bulk**" mineral also fails to 501 capture experimental (Ge/Si)_{fluid} behavior. In this situation, fluid interaction with the total 502 seed composition (0.28 µmol mol⁻¹) predicts a faster decrease in (Ge/Si)_{fluid} to values lower 503 than observed in the experiment.

For both Ge/Si and δ^{30} Si, the "surface" exchange scenario involving fluid interaction 504 505 with a co-evolving mineral surface offers the most accurate representation of the high surface 506 area data. The optimal number of timesteps to average over (i.e., the proxy for the fluid-507 mineral interaction depth or the portion of the recently-formed mineral surface in contact with the fluid) was identified through the same sensitivity analysis performed for δ^{30} Si (Fig. 4C, 508 509 **D**; Fernandez et al., 2019). This sensitivity analysis yielded a surface equilibration time 510 interval of > 14 days for the high surface area experimental Ge/Si data (Fig. 4C), distinctly larger than that determined for δ^{30} Si (1 day, Fig. 4D; Fernandez et al., 2019). The total mass 511 512 of newly formed precipitate generated on the high surface area seeds was estimated to correspond to a depth of 0.19 nm (Fernandez et al., 2019). For the δ^{30} Si study, a time interval 513 514 of 1 day implies fast kinetics and fluid interaction with only a very thin portion of the mineral 515 surface (~ 0.09 nm, Fernandez et al., 2019). Hence, for the same net amorphous silica 516 formation rates, a longer time interval (or a greater fluid-mineral surface interaction depth) 517 for Ge/Si implies slower overall kinetics and a relatively longer approach to equilibrium.

518 Therefore, differences in observed fluid δ^{30} Si and Ge/Si behavior throughout the 519 extent of the reaction can be interpreted from a "surface" exchange perspective. For δ^{30} Si, 520 faster kinetics and a smaller fluid–mineral surface interaction depth ultimately drives high 521 surface area δ^{30} Si_{fluid} to values more negative than the bulk mineral phase (-1.81 ± 0.03 %o),

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reflective of the fluid interacting with a strongly ³⁰Si-depleted mineral surface composition. 522 On the other hand, slower Ge kinetics and a larger fluid-mineral surface interaction depth 523 524 results in (Ge/Si)_{fluid} remaining at elevated values throughout the experimental duration. 525 Quick precipitation of amorphous silica compared to relatively sluggish Ge incorporation 526 results in the fluid interacting with a highly depleted Ge/Si mineral surface (Appendix B, Fig. 527 **B.1**). Up to 70% of the total Si precipitated out of solution is generated during the first day of 528 the experiment. Fluid interaction with this initially low mineral surface Ge/Si composition 529 shifts (Ge/Si)_{fluid} to values lower than would be predicted in a "no-back reaction" mass 530 exchange scenario. Due to the relatively small amount of mass precipitated compared to the 531 total mass of amorphous silica present in the system, the mineral surface is highly sensitive to 532 any minor incorporation of Ge. Thus, the surface composition is predicted in the model to 533 increase with time to higher Ge/Si ratios ((Ge/Si)_{ppt} = 2.81μ mol mol⁻¹) in agreement with 534 simple mass balance approximations using the experimental data (Table 2). The ability of the 535 "surface" option to better predict high surface area data supports a mass exchange between 536 the fluid and mineral surface as the principal driver of observed (Ge/Si)fluid. Further, a major finding from these numerical simulations is that Ge/Si and δ^{30} Si have different equilibration 537 538 timescales and, thus, represent two distinct "clocks". In this regard, Ge/Si may serve as a 539 potent (near)equilibrium tracer in a manner similar to the ²⁹Si equilibrium tracer (Zheng et al., 540 2019; Zhu et al., 2020).

This result implies quite distinct kinetic behavior between Ge and Si where Ge kinetic partitioning is notably slower. Therefore, substantial residence times or path lengths would be necessary to observe Ge incorporation into secondary phases in natural settings. At first glance this may appear to contradict a recent study by Perez-Fodich and Derry, 2020, who used a CrunchTope framework to model Ge/Si incorporation into kaolinite based on field observations. They suggested that overall fast precipitation rates of kaolinite and comparable 547 Ge and Si kinetics were necessary to explain observed ratios in weathering environments. 548 However, it should be clarified that Perez-Fodich and Derry (2020) did not directly model 549 kinetic Ge partitioning during the growth of kaolinite. Rather, they simply note that if 550 kaolinite growth is slow. Ge incorporation is slow and thus the fluid Ge/Si ratio remains 551 elevated. Our results are the first to directly illustrate Ge incorporation into secondary 552 minerals during growth, and clearly show that Ge kinetics are slow relative to Si. This present 553 study utilizes amorphous SiO₂, but the results open the possibility that slow Ge kinetics may 554 also exists for aluminosilicate clays. These findings suggest that the transport timescales in 555 natural systems may require re-evaluation in light of the unique behavior of Ge kinetics 556 relative to Si during amorphous silica formation using a direct simulation of Ge kinetics in the 557 modeling framework presented here.

558 Taking these simulations as a guide, we can now address a driving question in this 559 study: Is a rate-dependent fractionation framework sufficient to capture both Ge/Si and Si 560 stable isotope behavior simultaneously in the same system? The answer is a conditional "yes". The data-model comparison offers substantial evidence to suggest Ge/Si and δ^{30} Si are self-561 562 consistent during amorphous silica formation. However, this is predicated on the idea that Ge 563 in the fluid phase interacts with a very different component of the newly formed amorphous silica surface than its fluid δ^{30} Si counterpart. These findings have significant implications for 564 565 how the observed K_D is defined and interpreted when we extend out to longer timescales.

566 4.4 Forecasting Ge behavior over long timescales

567 This section uses the Ge trace model to forecast Ge behavior at longer (annual to 568 millennial) timescales based on our range of precipitation rates and mineral surface areas. 569 Since no data are available at these timescales for amorphous silica precipitation to validate 570 the model predictions, these results should be regarded as hypotheses that we present as a 571 driver for future research in Ge/Si partitioning during secondary silicate formation. The trace

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572 model was run out to 1000 years for all three surface areas, capturing timescales that can be 573 observed in a wide range of natural system. Only the bulk and surface fluid–mineral exchange 574 scenarios are used for these simulations as the no back-reaction model will never allow 575 dissolved Ge to re-equilibrate with the solid phase.

576 Overall, we observe a general trend where the observed partition coefficient, K_D 577 $((Ge/Si)_{solid}/(Ge/Si)_{fluid}$ where solid = bulk $(Ge/Si)_{am,silica}$ or cumulatively precipitated 578 (Ge/Si)_{ppt} amorphous silica) increases over longer timescales as Ge incorporation is allowed 579 to proceed (Fig. 5). This result corresponds with associated decrease in modeled (Ge/Si)_{fluid} to 580 lower values as a function of time (~ $1.2 \pm 0.2 \mu$ mol mol⁻¹ for the high surface area case, 581 Appendix C). The extent of Ge incorporation into the solid is strongly dependent on the rate 582 at which equilibrium is approached, which is coupled to the surface area. Importantly, overall 583 amorphous silica precipitation at these timescales is extremely slow and the system is 584 functioning at (near) equilibrium conditions. Thus, equilibrium exchange is driving observed 585 Ge/Si behavior. Despite the obvious limitations in our ability to independently validate such 586 forecasted Ge/Si partitioning over these timescales, our results consistently demonstrate that 587 Ge does eventually become incorporated into amorphous silica. Therefore, the general 588 observation of higher Ge/Si ratios in the solid phase during secondary mineral formation is 589 eventually recovered in our models at longer annual to decadal timescales.

590 On the experimental timescale, fluid phase δ^{30} Si and Ge/Si were found to be positively 591 correlated, increasing during early stages of amorphous silica growth. This observation goes 592 against the inverse relationship between the two tracers that has been previously documented 593 in the literature for secondary clay formation in field settings (Cornelis et al., 2010; Opfergelt 594 et al., 2010; Delvigne et al., 2016). There are potentially several reasons for this discrepancy. 595 Secondary clay formation rates are characteristically slow, as for kaolinite, which has a 596 precipitation rate that is roughly four orders of magnitude slower than amorphous silica (10⁻

^{13.6} mol m⁻² s⁻¹; Yang and Steefel, 2008). At slow enough precipitation rates, it could be 597 possible that Ge incorporation occurs at comparable timescales to δ^{30} Si fractionation and, 598 599 thus, generates the inverse relationship commonly observed. Results from our long-term Ge 600 trace model predictions suggest an alternative explanation for this discrepancy, which is linked to the extent of reactivity in the system and large differences in $\delta^{30}Si$ and Ge/Si 601 equilibration timescales. Field observations could potentially be biased towards equilibrated 602 603 systems where observed increases in secondary phase Ge/Si ratios, such as those reported 604 during storm events in the Rio Icacos watershed in Puerto Rico (Kurtz et al., 2011), may 605 reflect late-stage mineral recrystallization conditions. However, as we will discuss further in 606 section 4.7, an alternative explanation for such field observations could be associated with 607 faster Ge uptake reactions such as adsorption and coprecipitation onto iron hydroxides 608 (Pokrovsky et al., 2006).

609 Finally, results from the Ge trace model highlight the importance of Ge equilibrium 610 partitioning, which ultimately dominates the long-term evolution of fluid Ge/Si signatures. 611 Substantial evidence from both our experiments and model runs point to the role of the 612 mineral surface area in dictating the extent of reaction progress and associated Ge/Si 613 partitioning during amorphous silica precipitation onto pre-existing seeds. In other words, high surface areas (> 1 m² g⁻¹) "accelerate" whereas lower surface areas (< 1 m² g⁻¹) act as 614 615 "brakes" on the extent of Ge/Si partitioning. Despite the relatively sluggish Ge incorporation 616 rates observed in the experiments, we predict that fluid Ge/Si ratios will eventually shift to lower values typically observed in natural waters (~ $0.6 \pm 0.06 \mu$ mol mol⁻¹; Mortlock and 617 618 Froelich, 1987). The time that it will take to reach naturally observed Ge/Si ratios is only 619 approximated in our long-timescale simulations, but our results do appear to overlap with the 620 average fluid residence times of groundwaters (< 50 years old, Gleeson et al., 2015) and deep 621 marine sediment porewaters (Bard et al., 1989; Tréguer et al., 1995). From these simulations, 622 Ge/Si partitioning timescales are found to be strongly lagged compared to δ^{30} Si fractionation 623 in that Ge incorporation occurs at (near)equilibrium conditions. In other words, despite the 624 capability of both systems to express unique kinetic and equilibrium effects, the timescales 625 over which kinetic signatures are erased after reaching chemical equilibrium are predicted to 626 be quite different for Ge/Si and δ^{30} Si.

627 **4.5** The instantaneous partition coefficient, K_D^{inst} and observed rate dependence

628 4.5.1 Defining the instantaneous partition coefficient

Even under "chemostatic" conditions where mineral growth occurs under fixed saturation states and solute compositions, heterogeneity in the growing mineral surface has been observed for Sr/Ca during calcite precipitation (Tang et al., 2008). In the calcite literature, the effect of this mineral zoning on the instantaneous partition coefficient was accounted for by recasting the traditional method of calculating the partition coefficient (Eq. 5a) in terms of a Rayleigh distillation type evolution in the bulk as shown below (Eq. 5b):

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$$K_{D}^{\text{inst}} = \frac{(\text{Ge}/\text{Si})_{\text{am.silica}}}{(\text{Ge}/\text{Si})_{\text{aq}}}$$
(5a)

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$$\left(\frac{Ge}{Si}\right)_{\text{am.silica}} = \left(\frac{Ge}{Si}\right)_{\text{fluid},0} \times \frac{1 \cdot \left(\frac{Si}{Si_0}\right)_{\text{fluid}}^{K_D^{\text{inst}}}}{1 \cdot \left(\frac{Si}{Si_0}\right)_{\text{fluid}}}$$
(5b)

Here these two approaches to calculating K_D^{inst} are modified from the Tang et al. (2008) study to apply to our Ge/Si data for amorphous silica precipitation. In Eq. 5b, $\left(\frac{Ge}{Si}\right)_{fluid,0}$ represents the initial fluid Ge/Si ratio, while $\left(\frac{Si}{Si_0}\right)_{fluid}$ represents the fraction of Si remaining in solution (Si = concentration of dissolved Si at time t, Si_{0,aq} = initial SiO_{2(aq)} concentration), and $\left(\frac{Ge}{Si}\right)_{am.silica}$ represents a running estimate of bulk amorphous silica composition through time (**Table 2**). Eq. 5b can then be rearranged to solve for the K_D^{inst} at each sample interval (Appendix D). Our experiments incorporate the additional complexity of "free-drifting" 644 conditions, such that the instantaneous partition coefficient (K_D^{inst}) for Ge may be strongly 645 influenced by heterogeneity in the growing mineral surface. To encapsulate all of these 646 considerations in the calculation of K_D^{inst} , we adopt two distinct estimates across all three 647 surface areas.

648 These approaches to calculating K_D^{inst} yield distinct values for each surface area tested, 649 implying that the partition coefficient appears to be rate dependent (Fig. 6). All calculated partition coefficients are << 1, reflecting the artificially high starting fluid Ge/Si ratios that are 650 651 caused by an initial (Ge/Si)_{fluid} that is much higher than the initial ratio of the seed crystals. K_{D}^{inst} does not seem to be significantly influenced by the co-evolution of the fluid and bulk 652 653 solid Ge/Si ratio during amorphous silica growth. In all cases, the differences between the two 654 calculated partition coefficients increase with decreasing precipitation rates. Similar observations for a rate dependent K_D^{inst} have been reported in the carbonate literature for Sr 655 trace element partitioning during calcium carbonate formation (Lorens, 1981; Tesoriero and 656 657 Pankow, 1996; Huang and Fairchild, 2001; Nehrke et al., 2007; Tang et al., 2008, 2012; Böhm et al., 2012; Gabitov et al., 2014; AlKhatib and Eisenhauer, 2017). Rate dependence in 658 659 these studies were interpreted to reflect greater incorporation of the trace element into the 660 growing solid at faster precipitation rates. However, based on information from Ge trace model results at both experimental and longer timescales, the observed rate dependence 661 662 cannot be interpreted in the same manner.

663 4.5.2 K_D^{inst} rate dependent behavior for equilibrium tracers

For the purpose of this discussion and to allow for these results to be extended to other systems, our low experimental K_D^{inst} values determined in **section 4.5.1** were renormalized to reflect a starting (Ge/Si)_{fluid} equal to the bulk solid phase composition (0.28 – 0.64 µmol mol⁻ ¹). For the experimentally determined values, K_D^{inst} were normalized by applying the difference between the initial measured fluid and bulk Ge/Si ratios (i.e. (Ge/Si)_{fluid,init} –

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669 (Ge/Si)_{am.silica,init}) to the rest of the measured (Ge/Si)_{fluid} values as a function of time. 670 Normalization of numerically estimated K_D^{inst} values was invoked in the Ge trace model by 671 setting (Ge/Si)_{fluid} equal to that of the bulk in the initial conditions and then running the model 672 out to identical short (35 days) and long (1000 year) times under a "surface" mass exchange 673 scenario. This renormalization approach is justifiable considering that the Ge trace model 674 successfully captures observed (Ge/Si)_{fluid} variability over the experimental duration (**Fig.** 675 **4A**).

Results of normalized K_D^{inst} (denoted from here on as K_D^*) are shown in Fig. 7 as a 676 function of the amorphous silica precipitation rate (R_p) using both the bulk (Fig. 7A) and 677 678 cumulatively precipitated (Fig. 7B) solid compositions over longer timescales. Over the experimental duration, observed K_D^* is shown to decrease as R_p decreases for all surface area 679 conditions (Fig. 7C). However, the relationship between K_D^* and R_p eventually flips as we 680 681 extend farther into (near)equilibrium conditions during late-stage mineral growth, reflecting a 682 transition from kinetic to equilibrium partitioning regimes. In the kinetic regime, quasi-683 conservative Ge behavior coupled to active silica precipitation results in a newly formed solid Ge/Si that is initially Ge-depleted, resulting in a decrease in K_D^* as a function of R_p (Fig. 7C). 684 685 Although Ge shows similar rate dependence to those seen in other trace elements (notably Sr during carbonate formation), the factors underlying this observed correlation between K_{D}^{*} and 686 687 R_p are quite distinct. For the trace element Sr, observed decreases in K_D^{inst} as a function of the net precipitation rate reflect uptake rates that are fast enough to "keep up" with carbonate 688 689 formation (Gabitov and Watson, 2006; Tang et al., 2008; Wasylenki et al., 2005; AlKhatib 690 and Eisenhauer, 2017). The opposite is true for Ge, where slow uptake compared to relatively fast silica precipitation drives the overall relationship between observed K_D^{inst} and net 691 692 precipitation rates. Ultimately, this kinetic regime is temporary (lasting between a few days to 693 a month) and quickly transitions into the equilibrium regime characterized by extensive Ge 694 incorporation at (near) equilibrium conditions where Si concentrations no longer change with
695 time (Fig. 7 A,B).

696 These coupled experimental observations and long-term model predictions largely support an observed rate-dependence in the K_D^{inst} for amorphous silica that is a direct 697 698 consequence of large differences between Si vs. Ge equilibration timescales. This is a major 699 finding of the study in that: (1) it distinguishes Ge partitioning behavior from other trace elements, notably Sr but also Ba²⁺ and Cd²⁺ (Tesoriero and Pankow, 1996; Prieto et al., 1997), 700 701 as a function of the timescale of incorporation; (2) it presents for the first time evidence of 702 rate-dependent behavior in Ge partition coefficients; and (3) it provides a "conservative-like" behavior alternative for interpreting rate dependence in the observed K_D^{inst} for other trace 703 704 elements with similarly slow incorporation kinetics. Thus, variability in the observed K_D^{inst} values we see in nature could reflect a balance between a "conservative" kinetic K_D, and a 705 706 "final" equilibrium K_D.

707 **4.6 Toward a Ge/Si and \delta^{30}Si multi-tracer approach**

708 Evidence from the experimental data and numerical batch model simulations support the 709 idea of Ge/Si as an equilibrium tracer. Based on this revised viewpoint, we are now poised to 710 interpret the δ^{30} Si vs Ge/Si relationship observed during amorphous silica precipitation (Fig. 711 2). High precipitation rates at the beginning of the reaction result in a strong, positive 712 correlation between δ^{30} Si and Ge/Si until maximum isotope kinetic enrichment is obtained. Afterwards, as precipitation rates begin to slow down considerably, high surface area δ^{30} Si_{fluid} 713 714 and (Ge/Si)_{fluid} display a negative correlation where increasing contributions from equilibrium 715 fractionation return δ^{30} Si_{fluid} to values equivalent to or even lower than the starting 716 composition (referred to as isotopic re-equilibration). Based on the bulk compositions of our 717 experiments, the (Ge/Si)_{fluid} at equilibrium is predicted to range from ~0.02 to 0.05 µmol mol⁻ ¹. The timescales for δ^{30} Si and Ge/Si fractionation are thus drastically different from one 718

another. δ^{30} Si both kinetically fractionates and experiences subsequent re-equilibration before Ge equilibrium partitioning is even initiated. These δ^{30} Si vs Ge/Si relationships capture a broad range of secondary mineral progression where high δ^{30} Si and Ge/Si ratios reflect early stages of formation and low δ^{30} Si and Ge/Si ratios reflect extensive equilibration.

723 Extending to timescales common in natural settings, a combination of trace element 724 model fluid Ge/Si ratios under a "surface" mass exchange scenario (section 4.2) and transient batch model fluid δ^{30} Si (Fernandez et al., 2019) were run out to 20 years for all surface area 725 726 cases (Fig. 8). This timescale reflects a typical age of older groundwaters in kinetically 727 limited weathering environments (Rademacher et al., 2001, 2005; Manning et al., 2012). The 728 Ge/Si and δ^{30} Si models both predict the extent of equilibrium partitioning to be dependent on 729 the surface area or rate at which the reaction is allowed to proceed. Precipitation results in a quasi-hysteresis loop that reflects an interplay between rapid δ^{30} Si kinetic fractionation and 730 subsequent re-equilibration towards equilibrium values ($\delta^{30}Si_{fluid} = -2.73 \pm 0.07\%$ calculated 731 732 from the starting fluid ratio, Fernandez et al., 2019, and equilibrium fractionation factor, 733 Stamm et al., 2019) and a slower, continued approach towards predicted (Ge/Si)fluid equilibrium values (~0.02 to 0.05 µmol mol⁻¹) over much longer timescales. Precipitation 734 735 onto lower surface area amorphous silica seeds significantly slows down growth rates and prolongs both Ge/Si and δ^{30} Si disequilibrium. Thus, lower surface area seeds are able to retain 736 kinetic signatures over much longer timescales. 737

Another way to visualize these δ^{30} Si vs Ge/Si relationships is through the respective observed Si isotope fractionation factor, (here described via the isotope difference $\Delta_{solid-fluid}$ $\approx 1000 \times \ln \alpha$) vs. the normalized Ge partition coefficient, K_D^{*}, which is here presented in terms of the cumulative precipitate compositions (**Fig. 9**). In $\Delta_{solid-fluid}$ vs. K_D^{*} space, a fairly robust negative correlation is observed between the fractionation factor and partition coefficient throughout the course of the experiment. Early stages of amorphous silica growth are associated with an increase in $\Delta_{solid-fluid}$ (due to mixed kinetic and equilibrium fractionation) and a decrease in K_D^{inst} (due to Ge conservative-like behavior). Late stage evolution of high surface area $\Delta_{solid-fluid}$ and K_D^{inst} from model predictions nicely illustrate increasing contributions from Ge/Si equilibrium partitioning (driving the K_D^{inst} up to higher values) as Si stable isotopes approach (near) equilibrium conditions. Based on these findings, fluid Ge/Si and δ^{30} Si may provide significant insight into the fluid residence times within the weathering zone.

Finally, we suggest that δ^{30} Si vs Ge/Si relationships can give constraints on the 751 752 weathering intensity of a system and the extent of secondary silicate formation where less intense weathering, kinetically limited environments would express high δ^{30} Si and Ge/Si 753 754 signatures and vice versa for more intensely weathered, transport-limited systems. This 755 application has already been demonstrated for a high weathering intensity, tropical catchment 756 in Costa Rica (Baronas et al., 2020). Therefore, Ge/Si as a (near)equilibrium tracer serves as a complement to δ^{30} Si, which has been demonstrated in the recent literature to be a tracer of 757 758 kinetic processes (Geilert et al., 2014; Roerdink et al., 2015; Oelze et al., 2015). Further, the unique behavior of Ge vs. δ^{30} Si with respect to mineralogy serves an added advantage in that 759 760 the dissolution and precipitation of a given Ge-bearing silicate can be uniquely identified 761 within a given system. This combination of complementary trace element and stable isotope 762 systems represents a path forward in the quantitative analysis of weathering environments, 763 with its potential only now starting to be realized in the literature (Cardinal et al., 2010; 764 Cornelis et al., 2010; Opfergelt et al., 2010; Delvigne et al., 2016; Baronas et al., 2018).

765 **4.7** Ge/Si field signatures from a mixed kinetic-equilibrium partitioning perspective

Finally, we take the opportunity to consider observations from a variety of field-scale systems for which the present study may offer new insight. In transport-limited weathering environments such as large sedimentary basins where groundwater ages can reach millennial 769 timescales (Sturchio et al., 2004), amorphous silica is commonly observed as a cementation or accretion between grains and serves as an important ³⁰Si depleted reservoir (Basile-Doelsch et 770 771 al., 2005). In this context, timescales may be sufficient to allow slow Ge incorporation to 772 serve as a Ge terrestrial sink. At shorter timescales in kinetically limited weathering 773 environments, amorphous silica formation is less common and most likely a less important 774 control on observed Ge/Si signatures relative to other secondary phases. However, the range of surface areas encapsulated by this study $(0.07 - 50.00 \text{ m}^2 \text{ g}^{-1})$ overlap with those observed 775 in both basaltic $(2 - 24 \text{ m}^2 \text{ g}^{-1}; \text{Navarre-Stichler et al., 2015})$ and granitic (0.1 to 1.5 m² g⁻¹) 776 777 White et al., 1996) regolith. Thus, our results may be relevant to other secondary silicates and suggest that if slow Ge kinetics are indeed applicable to a variety of secondary clays, then 778 779 long subsurface fluid transit times would be necessary to create low stream Ge/Si 780 compositions as a result of Ge incorporation into these minerals. If Ge incorporation into secondary clays is slow because of kinetic limitations on either mineral neoformation or Ge 781 782 incorporation into neoformed phases then adsorption onto Fe and Al (oxy)hydroxides may 783 play a more important role on shorter timescales (Mortlock and Froelich, 1987; Kurtz et al., 784 2002; Schribner et al., 2006). For instance, batch experiments showed fast Ge uptake rates 785 during for Ge adsorption onto goethite, with ~80% of dissolved Ge removed from solution 786 over the span of 10 minutes and complete Ge incorporation by 100 minutes during coprecipitation with FeOH (Pokrovsky et al., 2006). 787

Slow Ge kinetics and mixed kinetic and equilibrium Ge partitioning may also hold relevance for the signatures of marine diagenesis. Observations of Ge decoupling from Si at depth in marine sediments rich in biogenic opal spanning 100,000s of years (Hammond et al., 2000; King et al., 2000; Baronas et al., 2016) have generally been interpreted as reflecting a complex balance between biogenic silica dissolution and (re)precipitation of amorphous silica along with potentially iron-rich clays. From the perspective of our experimental results,

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decoupling of Ge from Si could reflect the large disparity between fast Si precipitation
kinetics and slow Ge recrystallization, yielding observations of Ge-enriched porewaters with
depth into the sediment profile (King et al., 2000).

797 Finally, results from this study may offer utility in the interpretation of high Ge/Si ratios 798 found in hydrothermal waters (Arnórsson, 1984; Criaud and Fouillac, 1986; Evans and Derry, 799 2002; Han et al., 2015). Geothermal waters from active geothermal systems have high, but 800 variable (Ge/Si)_{fluid}, which was explained using a Rayleigh model for the precipitation of Ge-801 depleted quartz along a cooling path(s) (Evans and Derry 2002). Our findings agree with this 802 interpretation where the formation of Ge-depleted amorphous silica would result in elevated 803 (Ge/Si)fluid throughout the experimental duration. However, the successful application of our 804 trace model to the experimental data suggest that a Rayleigh model could be overly simplistic 805 of an approach for amorphous silica where a back reaction is known to occur and would most 806 likely lead to an overestimation of the extent of Ge/Si partitioning. Our combined modeling 807 and experimental study concludes that fluid interaction with the mineral surface dictates the 808 observed (Ge/Si)fluid over the timescales of mineral growth.

809 **5. CONCLUSIONS**

810 This study reports Ge/Si fractionation during amorphous silica precipitation across a range 811 of precipitation rates under highly controlled laboratory settings. Our findings show that Ge 812 incorporation kinetics are very slow (~ 10 orders of magnitude slower than silica precipitation 813 rates) and, as a result, gives the appearance of conservative behavior over short timescales (~ 814 30 days). A major consequence of this observed lag between fast Si kinetics and Ge 815 conservative-like behavior at early stages of mineral growth is the appearance of rate 816 dependence behavior in the observed partition coefficient, K_D. Model results imply that Ge/Si 817 fractionation is controlled strictly by equilibrium processes, making it a unique equilibrium 818 tracer. Over long timescales, Ge/Si equilibrium partitioning appears to exhibit dependence on 819 the reaction rate with fluid Ge/Si returning to equilibrium values faster during uptake onto higher surface area seeds relative to lower surface area seeds. A combined $\delta^{30}Si$ and Ge/Si 820 821 multi-tracer approach has the potential to provide important constraints on weathering 822 intensity, fluid residence times and the amount of secondary silicate formation taking place in 823 the weathering zone. Finally, successful application of the trace element batch model to the 824 experimental dataset over a range of surface areas suggests that the framework developed in 825 the CrunchTope software under the assumption that trace elements behave analogously to 826 stable isotopes is valid for germanium. Our results extend the utility of CrunchTope for 827 modeling both kinetic and equilibrium trace element partitioning in addition to stable isotope 828 fractionation.

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830 ACKNOWLEDGMENTS

832 This material is based upon work supported by the National Science Foundation Graduate 833 Research Fellowship Program under Grant No. DGE-1144245, NSF grant EAR 1660923, 834 l'Agence Nationale de la Recherche project ANR-17-MPGA-0009, and by the Chateaubriand 835 Fellowship of the Office for Science & Technology of the Embassy of France in the United 836 States. Special acknowledgment is given to Jérôme Gaillardet, Julien Bouchez, and the G2E 837 (Géochimie des Enveloppes Externes) group for their assistance and allowing us access to the 838 facilities at the Institut de Physique du Globe de Paris (IPGP) in Paris, France to perform the experiments and measurements necessary for this study. 839

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FIGURE CAPTIONS

1120 Figure 1. Dissolved silica concentration timeseries for the high (red circles), medium (green 1121 diamonds), and low (blue squares) surface area batch experiments (A) from Fernandez et al. (2019) and (**B**) corresponding measured fluid δ^{30} Si (open markers, Fernandez et al., 2019) 1122 and Ge/Si ratios (solid markers, this study) as a function of time for the ~30-day experiments. 1123 1124 Error bars correspond to 2 standard deviations for the Si stable isotope measurements. Ge/Si 1125 analytical uncertainty is within the marker sizes and correspond to 2% and 5% RSD for Ge 1126 and Si concentration measurements, respectively. Initial Ge/Si composition of the bulk phase 1127 is represented by the grey bar and red, green, and blue lines correspond to the evolving Ge/Si 1128 amorphous silica composition with time (see Table 2). Fluid Ge/Si ratios remain elevated with respect to the compositions of the high $(0.28 \pm 0.01 \ \mu \text{mol mol}^{-1})$, medium $(0.56 \pm 0.02 \ \mu \text{mol}^{-1})$ 1129 1130 μ mol mol⁻¹), and low (0.64 ± 0.02 μ mol mol⁻¹) surface area seed crystals.

Figure 2. Fluid δ^{30} Si as a function of Ge/Si ratio for the high (red circles), medium (green diamonds), and low (blue squares) surface area batches. Starting values are the points on the far left of the graph. A parabolic-type relationship characterizes the δ^{30} Si and Ge/Si variability in the high surface area batch, which represents fast δ^{30} Si re-equilibration relative to the rates of Ge/Si equilibrium partitioning (that are negligible over this experimental timespan). Error bars represent 2 standard deviation for the Si stable isotope data (Fernandez et al. 2019) and 2% and 5% RSD for Ge and Si concentration measurements used in Ge/Si calculations.

Figure 3. Fluid silicon (**A**) and germanium (**B**) concentrations as a function of the experimental duration (~35 days). Ge kinetic rate constant (log $k_{f,Ge}$) was determined based on a "best-fit" approach of the three mass exchange models (**section 4.2**) to the experimental data for a given Ge equilibrium constant (^{Ge}K_{eq} = 10^{-3.8198}) calculated based on an equilibrium thermodynamic model assuming ideal solid–state solution (Eq. 3) between quartz (SiO₂) and argutite (GeO₂). The range of Ge kinetic rate constants tested spanned roughly 7 orders of 1144 magnitude from $10^{-12.6}$ to $10^{-19.8}$ mol m⁻² s⁻¹. Errors are 2% and 5% RSD for Ge and Si 1145 concentration measurements used in Ge/Si calculations.

1146 Figure 4. Trace model simulations of fluid Ge/Si over the duration of the amorphous silica precipitation experiments across all surface areas for the three "no back reaction", "bulk", 1147 1148 and "surface" mass exchange scenarios (A). Fluid Ge/Si simulations are compared to previous simulations performed across the same exchange scenarios for fluid δ^{30} Si (B) 1149 1150 reported in Fernandez et al. (2019). Fluid δ^{30} Si show higher sensitivity to the different 1151 approaches in which the fluid can interact with the growing amorphous silica phase. The "surface" approach provides the best fit to the high surface area Ge/Si and δ^{30} Si. However, 1152 the time intervals (or fluid-mineral interaction depths) determined based on sensitivity 1153 analyses for Ge/Si and δ^{30} Si are distinct, > 14 days (C) and 1 day (D), respectively. Error bars 1154 1155 correspond to ± 2 SD for Si stable isotopes (C, D). Analytical uncertainty for Ge/Si 1156 measurements correspond to 1–3% RSD and are within the bounds of the symbols.

Figure 5. Long-term model simulations for the evolution of the observed Ge partition coefficient, K_D , over 1000 years for the high (**A**), medium (**B**), and low (**C**) surface area conditions. Predictions from the two different fluid–mineral equilibration scenarios; "**bulk**" (dashed line) and "**surface**" (solid line) are shown alongside the predicted equilibrium partition coefficient, K_D^{EQ} , equal to 12.8 (Eq. 3). In all cases, observed K_D behavior suggest that Ge partitioning is still far from equilibrium conditions at the end of the simulation.

1163 **Figure 6.** Instantaneous partition coefficient, K_D^{inst} , as a function of experimentally 1164 determined silica precipitation rates (presented here in log units; Fernandez et al., 2019) for 1165 the high (**A**), medium (**B**), and low (**C**) surface area amorphous silica precipitation batch 1166 experiments. The different K_D trends represent different methods of calculating the partition 1167 coefficient. To account for the evolving bulk amorphous silica composition with time in 1168 these "free-drifting" experiments, K_D^{inst} can be calculated either through the traditional method (Eq. 4a) or through a modified Rayleigh distillation approach (Eq. 4b, Tang et al.,2008).

Figure 7. Normalized K_D^{inst} (K_D^* , Ge/Si_{fluid} = Ge/Si_{solid}) as a function of silica precipitation 1171 rates (log R_p) for long term simulations (1000 years). K_D^* can be calculated using the "bulk" 1172 1173 or total solid (A) or cumulatively precipitated (B) composition. The predicted instantaneous 1174 partition coefficient at equilibrium, K_D equal to ~12.8 (Eq. 3), is represented by a yellow star. 1175 High, medium, and low surface area experimental data (~ 35 days) are shown as solid 1176 markers whereas numerical predictions are depicted as shaded gray areas. Mass balance and 1177 model predictions performed using the "surface" fluid-mineral mass exchange scenario are parsed out for each given surface area (C). At early times, K_D^* is observed to decrease with 1178 1179 decreasing precipitation rates as a result of quasi-conservative Ge behavior during the beginning of amorphous silica growth. At (near) equilibrium conditions, the relationship 1180 1181 between K_D and R_p flips from a positive to an inverse correlation where K_D increases with 1182 decreasing R_p.

Figure 8. Measured δ^{30} Si_{fluid} as a function of (Ge/Si)_{fluid} for the surface area batch experiments (depicted as markers) presented alongside trace model predictions for the respective surface area conditions over longer timescales, from 6 months to 20 years. Predicted equilibrium δ^{30} Si_{fluid} and (Ge/Si)_{fluid} are represented by a yellow star, corresponding to values of -2.73 ± 0.07 %*c*, calculated from the measured starting δ^{30} Si_{fluid} (Fernandez et al. 2019) and experimentally constrained equilibrium fractionation factor (Stamm et al., 2019), and ~0.02 – 0.05 µmol mol⁻¹, respectively.

1190 **Figure 9.** Calculated observed Si stable isotope fractionation factors, $\Delta_{cumul.ppt-fluid}$, as a 1191 function of the normalized instantaneous Ge partition coefficient, K_D^* (i.e. (Ge/Si)_{fluid} = 1192 (Ge/Si)_{am.silica}), using the composition of the cumulative precipitate as a function of time 1193 ((Ge/Si)_{ppt}). All surface area batch experiments (depicted as markers) are presented alongside

1194	trace model fluid $\Delta_{cumul.ppt-fluid}$ and K_D^{inst} predictions from the "surface" simulation (with a
1195	time interval > 14 days) from 6 months to 20 years. The equilibrium fractionation factor
1196	$(^{30/28}\Delta_{EQ(am,silica-fluid})$ and partition coefficient (D _{EQ}) for amorphous silica derives from Stamm
1197	et al. (2019) and this study (Eq. 3), respectively. At 20 years, $\Delta_{cumul.ppt-fluid}$ values suggest that
1198	Si stable isotopes are very close to equilibrium in the high surface area case whereas observed
1199	${K_D}^*$ values at the end of the simulation show that the system is still far from equilibrium for
1200	Ge. These results further highlight the distinct equilibration timescales between Ge/Si and
1201	δ^{30} Si.







faster Ge kinetics













Table 1. Starting conditions for all three amorphous silica precipitation batch experiments

Physical parameters	High SA	Med SA	Low SA
$SiO_{2(aq)} [mM]^*$	5.3 ± 0.7	5.3 ± 0.4	5.3 ± 0.5
Ge(OH) ₄ [µM] [‡]	0.043 ± 0.001	0.044 ± 0.001	0.046 ± 0.001
$Ω [log Q/K]^{¥}$	-3.95	-3.95	-3.95
GeOH _{4(aq)} [µg] [‡]	0.157 ± 0.003	0.80 ± 0.02	0.83 ± 0.02
GeO _{2(s)} [µg]	0.166 ± 0.003	2.90 ± 0.06	3.35 ± 0.07
$GeO_{2(s)}$: $GeOH_{4(aq)} [\mu g/\mu g]^{\dagger}$	1.06 ± 0.03	3.6 ± 0.1	4.0 ± 0.1
S [m ²]*	25 ± 8	0.54 ± 0.02	0.31 ± 0.02

* Fernandez et al. (2019)

Measured fluid Ge concentrations with an analytical uncertainty of 2% RSD.

¥ Saturation states for GeO₂ calculated using CrunchTope

[†] solid to fluid mass ratio calculated as the initial amount of Ge present in both the amorphous silica seed and fluid phase (GeOH₄). Error calculated based on standard error propagation using 2% RSD analytical uncertainty for Ge concentrations measurements.

No.	time	Si(OH)4 ^(a)	Ge(OH)4 ^(b)	NGeO2(ppt) ^(c)	NGeO2(am.silica) ^(d)	log R _p ^{Si (a)}	log R _p ^{Ge (e)}	(Ge/Si) _{fluid} f	(Ge/Si)ppt ^g	(Ge/Si) _{am.silica} ^h	KD ^{inst (i)}
	days	μM	pМ	pn	noles	mole	$m^{-2} s^{-1}$		µmol/mol		bulk/fluid
High surface area batch (50 $m^2 g^{-1}$)											
1	0.00	5277 ± 700	42776 ± 856		2291 ± 46			8.11 ± 0.13		0.28 ± 0.09	0.035 ± 0.006
2	0.02	5092 ± 500	42599 ± 852	52 ± 1207	2343 ± 1208	-9.48 ± 0.5	-14.9 ± 1.4	8.37 ± 0.10	2 ± 23	0.28 ± 0.52	0.034 ± 0.018
3	0.11	4600 ± 600	42855 ± 858	80 ± 1211	2371 ± 1711	-9.82 ± 0.1	-15.5 ± 1.2	9.32 ± 0.13	1 ± 15	0.28 ± 0.72	0.031 ± 0.022
4	0.19	4266 ± 700	41908 ± 838	169 ± 1199	2461 ± 2089	-9.90 ± 0.4	-15.4 ± 0.9	9.82 ± 0.16	2 ± 7	0.29 ± 0.85	0.032 ± 0.028
5	0.93	3375 ± 900	43382 ± 868	143 ± 1206	2434 ± 2413	-10.51 ± 0.5	-16.1 ± 0.9	12.85 + 0.27	1 ± 8	0.29 ± 1	0.024 ± 0.029
6	1.00	3311 ± 100	40579 ± 812	314 ± 1188	2605 ± 2689	-10.33 ± 0.6	-15.8 ± 0.6	12.25 ± 0.04	2 ± 4	0.31 ± 1.03	0.026 ± 0.027
7	2.00	2870 + 600	42451 ± 849	271 ± 1175	2562 ± 2935	-10.92 ± 0.7	-16.1 ± 0.6	14.79 ± 0.21	2 ± 4	0.30 ± 1.15	0.022 ± 0.027
8	8.87	2272 ± 200	43638 ± 873	262 ± 1218	2553 ± 3177	-11.65 ± 0.7	-16.8 ± 0.7	19.21 ± 0.09	1 ± 4	0.30 ± 1.25	0.015 ± 0.020
9	13.88	2193 ± 500	39336 ± 787	488 ± 1175	2779 ± 3387	-12.20 ± 0.7	-16.7 ± 0.4	17.93 ± 0.23	3 ± 2	0.33 ± 1.22	0.020 ± 0.025
10	18.95	2172 ± 400	39278 ± 786	530 ± 1112	2821 ± 3565	-12.49 ± 0.6	-16.8 ± 0.3	18.08 ± 0.18	3 ± 2	0.33 ± 1.26	0.019 ± 0.025
11	31.08	2051 ± 400	38855 ± 777	586 ± 1105	2877 ± 3733	-12.47 ± 0.7	-17.0 ± 0.3	18.95 ± 0.20	3 ± 2	0.34 ± 1.30	0.018 ± 0.025
seedini	t									0.28 ± 0.01	
seedfin	al									0.33 ± 0.02	
Mediu	m surface	area batch (0	$(127 m^2 g^{-1})$								
1	0.00	5334 ± 400	45631 ± 879		39982 ± 800			8.55 ± 0.08		0.56 ± 0.02	0.066 ± 0.005
2	1.83	4565 ± 400	42161 ± 843	994 ± 1243	40976 ± 1478	-8.62 ± 0.5	-13.9 ± 0.1	9.24 ± 0.09	5 ± 1	0.57 ± 0.04	0.063 ± 0.006
3	2.90	4144 ± 800	43658 ± 873	755 ± 1214	40737 ± 1912	-8.63 ± 0.6	-14.2 ± 0.2	10.53 ± 0.19	2 ± 2	0.57 ± 0.05	0.056 ± 0.013
4	4.23	3696 ± 500	43641 ± 873	890 ± 1235	40872 ± 2276	-8.70 ± 0.9	-14.3 ± 0.1	11.81 ± 0.14	2 ± 1	0.57 ± 0.06	0.049 ± 0.008
5	4.95	3618 ± 500	42024 ± 840	1406 ± 1212	41388 ± 2579	-9.04 ± 0.6	-14.2 ± 0.1	11.62 ± 0.14	3 ± 1	0.58 ± 0.06	0.051 ± 0.008
6	9.00	3219 ± 400	40454 ± 809	1901 ± 1167	41883 ± 2579	-9.23 ± 0.8	-14.3 ± 0.2	12.57 ± 0.13	3.2 ± 0.7	0.58 ± 0.07	0.048 ± 0.007
7	14.79	3091 ± 700	41350 ± 827	1815 ± 1157	41797 ± 3058	-9.80 ± 1.1	-14.6 ± 0.2	13.38 ± 0.23	2.9 ± 0.7	0.58 ± 0.07	0.046 ± 0.012
8	27.95	2948 ± 600	39346 ± 787	2397 ± 1142	42380 ± 3264	-10.13 ± 1.1	-14.7 ± 0.3	13.35 ± 0.20	3.6 ± 0.5	0.59 ± 0.08	0.046 ± 0.012
9	30.00	2955 ± 500	42548 ± 851	1792 ± 1159	41774 ± 3463	-10.09 ± 0.9	-14.8 ± 0.2	14.40 ± 0.17	2.6 ± 0.7	0.58 ± 0.08	0.042 ± 0.009
seed										0.56 ± 0.02	
Low st	urface are	a batch (0.072	$m^2 g^{-1}$								
1	0.00	5298 ± 500	45957 ± 919		46054 ± 921			8.7 ± 0.1		0.64 ± 0.02	0.074 ± 0.008
2	1.83	4686 ± 500	44345 ± 887	514 ± 1277	46567 ± 1575	-8.47 ± 0.2	-14.0 ± 0.4	9.46 ± 0.11	3 ± 3	0.64 ± 0.03	0.069 ± 0.008
3	2.90	4394 ± 400	49849 ± 997	-724 ± 1334	45330 ± 2064	-8.54 ± 0.3		11.34 ± 0.09	-2 ± 2	0.62 ± 0.05	0.056 ± 0.006
4	4.23	4194 ± 600	43084 ± 862	1042 ± 1318	47095 ± 2449	-8.76 ± 0.6	-14.0 ± 0.1	10.27 ± 0.14	3 ± 1	0.65 ± 0.05	0.065 ± 0.011
5	4.95	4080 ± 300	44194 ± 884	883 ± 1234	46936 ± 2742	-8.70 ± 0.5	-14.2 ± 0.1	10.83 ± 0.08	2 ± 1	0.65 ± 0.06	0.060 ± 0.006
6	9.00	3895 ± 300	45226 ± 905	748 ± 1265	46802 ± 3020	-9.28 ± 0.7	-14.5 ± 0.2	11.61 ± 0.08	2 ± 2	0.64 ± 0.06	0.056 ± 0.006
7	14.79	3817 ± 400	43839 ± 877	1187 ± 1260	47241 ± 3272	-9.72 ± 1.1	-14.49 ± 0.03	11.48 ± 0.11	3 ± 1	0.65 ± 0.07	0.057 ± 0.007
8	27.95	3618 ± 500	43555 ± 871	1363 ± 1236	47416 ± 3498	-9.77 ± 1.1	-14.71 ± 0.04	12.04 ± 0.14	2.8 ± 0.9	0.65 ± 0.07	0.055 ± 0.009
9	30.00	3610 ± 700	41984 ± 840	1833 ± 1210	47887 ± 3701	-9.70 ± 0.9	-14.6 ± 0.2	11.63 ± 0.19	3.7 ± 0.7	0.66 ± 0.08	0.059 ± 0.013

 Table 2. Germanium data for amorphous silica precipitation experiments

seed

 0.64 ± 0.02

- a. Additional details on dissolved silica concentrations, saturation states, precipitation rates, evolving surface area, and Si stable isotope ratios can be found in Fernandez et al. (2019)
- b. Measured fluid Ge concentrations with associated errors of $\pm 2\%$ RSD.
- c. Cumulative mass of amorphous GeO₂ precipitated out of solution. Values determined by subtracting the picomoles Ge in solution at time, t, from initial amount in solution, at t=0.
- d. Total mass amorphous silica present in the system with associated errors calculated using error propagation.
- e. Time-averaged precipitation rates for GeO₂ normalized to the surface area: $R_p^{Ge} = \frac{N_{GeO_2(ppt)_{t_I}} N_{GeO_2(ppt)_{t_I}}}{s \cdot \Delta t_{II-I}}$ (see eqn.5 in Fernandez et al., 2019 for further details). Uncertainty determined via standard error propagation.
- f. Measured fluid Ge/Si ratios where uncertainty determined using error propagation of the analytical uncertainties for Si (\pm 5% RSD) and Ge (\pm 2% RSD), respectively.
- g. Ge/Si ratios of the cumulatively precipitated amorphous silica. Determined through mass balance calculations using the cumulative mass of amorphous GeO₂ removed (N_{GeO2(ppt)}) and SiO2 (N_{SiO2(ppt)}; **Table 2 in Fernandez et al., 2019**). Uncertainty calculated using standard error propagation according to sum of squares.
- h. Amorphous silica Ge/Si ratios were estimated by tracking the total amount of GeO_2 and SiO_2 accumulating in the growing bulk ($n_{Ge,SiO2, bulk(t=0)} + n_{Ge,SiO2, cumulative(t)}$). Uncertainty calculated via error propagation according to the sum of squares using both the analytical error for the initial seeds and measured fluid Ge and Si uncertainties.
- i. The instantaneous partition coefficient calculated as $\frac{\frac{(Ge'_{Si})_{am.silica}}{(Ge_{Si})}}{\frac{(Ge'_{Si})_{am.silica}}{(Ge'_{Si})}}$, monitored throughout the course of the reaction for an evolving bulk solid phase.

j. Normalized instantaneous partition coefficients for an initial Ge/Si_{fluid} ratio equal to Ge/Si_{solid} and error calculated using Monte Carlo.

Parameters	units	conservative	Ge incorporation
reaction order		3.5	3.5
duration		35 days	35 days
			1 to 1000 years
timestep	hours	9.6	9.6
Т	°C	25	25
pH		7.33	7.33
Specific surface area	$m^2 g^{-1}$	50	50
		0.127	0.127
		0.072	0.072
Si(OH) _{4(aq)} ^a	mM	5.277	5.277
Ge(OH) _{4(aq)} ^b	mM	4.2776 x 10 ⁻⁵	4.2776 x 10 ⁻⁵
$\log k_{f(SiO2)}^{c}$		-9.67	-9.67
$\log k_{f(GeO2)}^{d}$		-	-19.7
log K _{eq(SiO2)} ^e		-2.7135	-2.7135
log K _{eq(GeO2)} ^f		-	-3.8198
(Ge/Si) _{fluid}	µmol mol ⁻¹	8.11	8.11
		0.28 (high)	0.28 (high)
(Ge/Si) _{am.silica}	µmol mol ⁻¹	0.56 (medium)	0.56 (medium)
		0.64 (low)	0.64 (low)
$\mathrm{D}_{\mathrm{EQ}}{}^{\mathrm{g}}$		-	0.08
${\rm D_{kin}}^{,{\rm h}}$		-	9.3×10^{-11}

Table 3. Initial conditions for the Ge, trace element batch model

a. Measured starting dissolved Si concentrations from Fernandez et al. (2019).

b. Measured starting dissolved Ge concentrations from this study.

c. Rimstidt and Barnes (1980)

d. Determined through taking a best fit of the experimental fluid Ge/Si data.

e. Gunnarsson and Anórsson (2000)

f. Estimated using Evans and Derry (2002) equilibrium model for germanium bearing quartz (Section 2.3, Eq. 3).

g. Equilibrium partition coefficient (D_{EQ}) calculated as the ratio between GeO_{2(am)} and SiO_{2(am)} equilibrium constants, $\frac{\kappa_{eq,GeO_2}}{\kappa_{eq,SiO_2}}$.

h. Kinetic partition coefficient calculated as the ratio between $\text{GeO}_{2(\text{am})}$ and $\text{SiO}_{2(\text{am})}$ precipitation rate constants: $\frac{k_{f,GeO_2}}{k_{f,GeO_2}}$

k_{f,SiO2}.